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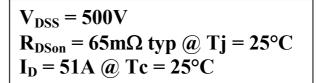


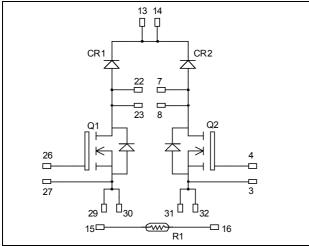






# Dual Boost chopper **MOSFET Power Module**





### 29 16 32 13

All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

#### **Application**

- AC and DC motor control
- Switched Mode Power Supplies
- **Power Factor Correction**

#### **Features**

- Power MOS 7<sup>®</sup> MOSFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
- Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a single boost of twice the current capability
- **RoHS Compliant**

#### **Absolute maximum ratings**

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		500	V
Ţ	Continuous Dusin Comment	$T_c = 25^{\circ}C$	51	
$I_D$	Continuous Drain Current	$T_c = 80$ °C	38	A
$I_{DM}$	Pulsed Drain current		204	
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		78	mΩ
$P_{D}$	Maximum Power Dissipation $T_c = 25^{\circ}C$		390	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		51	A
$E_{AR}$	Repetitive Avalanche Energy		50	m I
$E_{AS}$	Single Pulse Avalanche Energy		3000	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 500V$ $T_j = 25^{\circ}C$			100	μА
		$V_{GS} = 0V, V_{DS} = 400V$ $T_j = 125^{\circ}C$	}		500	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 25.5A$		65	78	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 2.5 \text{mA}$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{V}$			±100	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		7000		
$C_{oss}$	Output Capacitance	$V_{\rm DS} = 25V$		1400		pF
$C_{rss}$	Reverse Transfer Capacitance	f=1MHz		90		
$Q_{\mathrm{g}}$	Total gate Charge	$V_{GS} = 10V$		140		·
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{Bus} = 250V$		40		nC
$Q_{gd}$	Gate – Drain Charge	$I_D = 51A$		70		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15V \\ V_{Bus} = 333V \\ I_D = 51A \\ R_G = 3\Omega$		21		
$T_{\rm r}$	Rise Time			38		ma
$T_{d(off)}$	Turn-off Delay Time			75		ns
$T_{\mathrm{f}}$	Fall Time			93		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$ , $V_{Bus} = 333V$ $I_D = 51A$ , $R_G = 3\Omega$		1035		Т
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			845		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$ , $V_{Bus} = 333V$ $I_D = 51A$ , $R_G = 3\Omega$		1556		
E <sub>off</sub>	Turn-off Switching Energy			1013		μJ

### Diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			600			V
$I_{PM}$	$I_{\rm DM}$   Maximim Reverse Leakage Current   $V_{\rm p}=600V$	V <sub>p</sub> =600V	$T_j = 25$ °C			350	μA
KWI		$T_j = 125$ °C			600	, -	
$I_{\mathrm{F}}$	DC Forward Current		$T_c = 70$ °C		80		A
17	Die le Ferren I Weltere	$I_F = 80A$	$T_i = 25^{\circ}C$		1.45		V
$V_{F}$	Diode Forward Voltage		$T_j = 125$ °C		1.35		V
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25$ °C		95		ns
ι <sub>rr</sub>	Reverse Recovery Time	$I_F = 80A$ $V_R = 300V$	$T_{j} = 125^{\circ}C$		115		113
$Q_{rr}$	Reverse Recovery Charge	di/dt=4500A/μs	$T_j = 25^{\circ}C$		5.2		μС
₹rr			$T_j = 125$ °C		8		μΟ



### Thermal and package characteristics

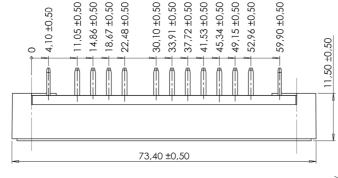
Symbol	Characteristic			Min	Тур	Max	Unit
$R_{\text{thJC}}$	Junction to Case Thermal Resistance		Transistor			0.32	°C/W
			Diode			0.8	C/ W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	
$T_{STG}$	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2	•	3	N.m
Wt	Package Weight				•	110	g

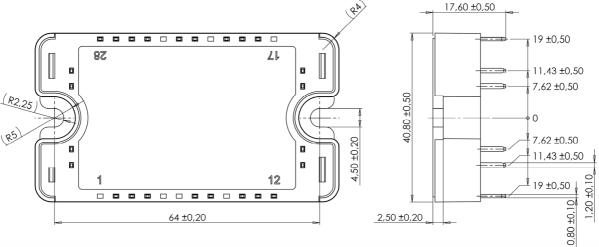
### Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 
$$R_{T}: \text{ Thermistor value at T}$$

### SP3 Package outline (dimensions in mm)



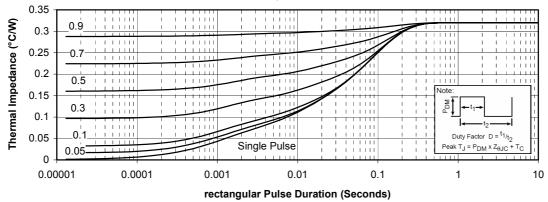


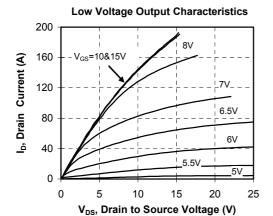
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

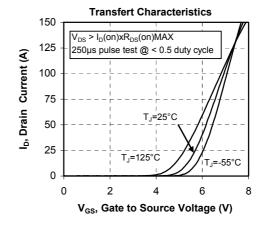


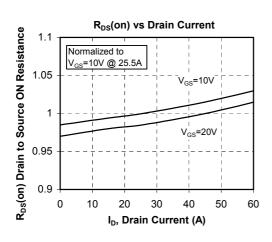
### **Typical Performance Curve**

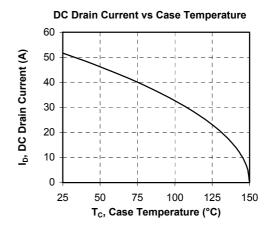
#### Maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



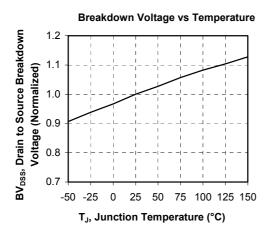


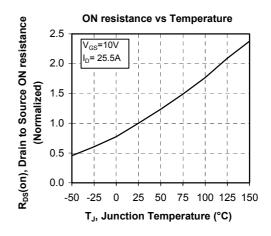


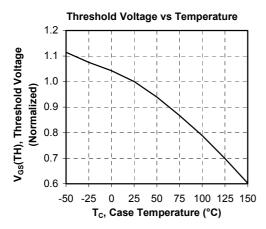


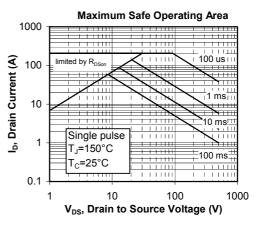


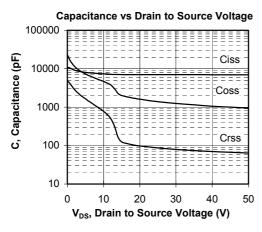


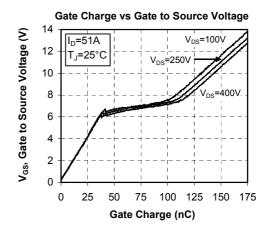




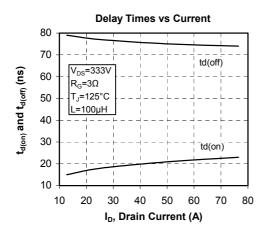


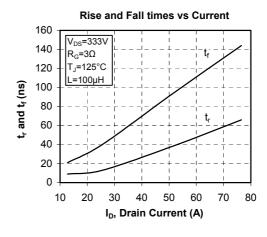


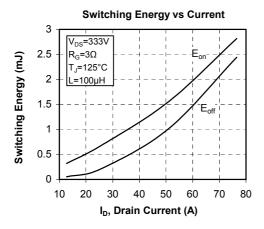


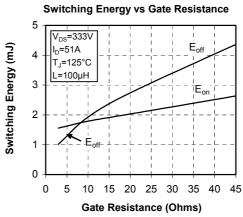


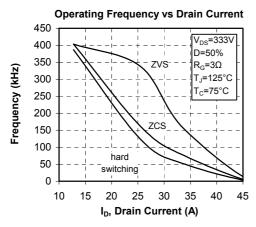


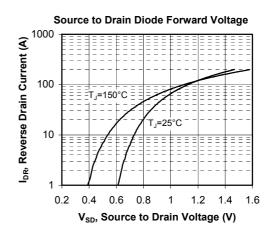












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